

Effect of annealing on the specific heat of optimally doped $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$

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Abstract. We report the temperature dependence of the low-temperature specific heat down to 400 mK of the electron-doped $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$ superconductors. We have measured two samples extracted from the same batch: first sample has been measured just after preparation with no additional heat treatment. The sample shows $T_c=20$ K, residual specific heat $\gamma_0=3.6$ mJ/mol K² and a Schottky-like contribution at low temperatures. A second sample has been annealed at 800 °C for two weeks and shows $T_c=25$ K and $\gamma_0=1.4$ mJ/mol K². By subtracting the lattice specific heat, from pure BaFe_2As_2 , the temperature dependence of the electronic specific heat has been obtained and studied. For both samples the temperature dependence of $C_{el}(T)$ clearly indicate the presence of low-energy excitations in the system. Their specific heat data cannot be described by single clean *s*- or *d*-wave models and the data requires an anisotropic gap scenario which may or may not have nodes.

1. Introduction

The discovery of superconductivity in FeAs-based materials[1, 2] has re-opened new interest in superconductivity research. Unfortunately, despite a large theoretical[3] and experimental[4] effort the nature of the superconductivity in these materials including the pairing mechanism and the symmetry of the order parameter remains unclear.

One way to address the nature of the superconductivity is to study the low-temperature heat capacity. The measurements of the temperature dependence of the specific heat and its magnetic field response in superconducting state give an important information about the symmetry of the order parameter[5, 6, 7, 8, 9, 10]. For optimally Co doped material[11] such a analysis suggest the presence of an anisotropic gap structure which may or may not have nodes (see Ref.[5, 6, 7, 8]). Moreover, the specific heat displays significant residual specific heat possibly coming from the non-superconducting fraction that is present in the system[6]. Thus, the heat capacity at very low temperatures is very sensitive on the quality of the crystals studied and it is very often dominated by a Schottky-like contribution[12]. This could make the the gap structure analysis quite complex.

In this paper, we present results of our specific heat studies of optimally doped $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$ samples. We have measured two samples extracted from the same batch: sample one has been measured just after growing and without any additional heat treatment. The sample shows $T_c=20$ K, residual specific heat $\gamma_0=3.6$ mJ/mol K^2 and a Schottky-like contribution at low temperatures. Sample two has been annealed at 800 °C for two weeks with $T_c=25$ K and $\gamma_0=1.4$ mJ/mol K^2 . For this material no Schottky term is observed (see Fig.1 inset). Then using similar approach as previously reported in Ref.[5, 6] we extract and study the full electronic T -dependence for these two samples.

2. Experimental details

Single crystals were grown out of FeAs flux with a typical size of about $2 \times 1.5 \times 0.2$ mm³[11]. They crystallize in well-formed plates with the [001] direction perpendicular to the plane of the crystals. The doping level was determined by microprobe analysis. After synthesis a second piece of the sample was annealed for two weeks at 800 °C while the first one has not been heat treated. The heat capacity was measured down to 400 mK using a thermal relaxation method implemented in a Quantum Design PPMS-9 device.

3. Results and discussion

Fig.1 shows the temperature dependence of the specific heat of the annealed and non-annealed $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$ samples. As may be seen the annealing process has increased T_c quite remarkably from 20 K for the non-annealed sample up to 25 K for the annealed one. It is worth noting the transition temperature of about 25 K is one of the highest reported within the Co doped Ba122 family. Above T_c the $C_p(T)$ curves indicate very similar temperature dependence of the phonon part in these two materials as expected. As may be seen from the inset of Fig.1 the annealing strongly suppress the residual specific heat γ_0 from 3.6 to 1.4 mJ/mol K^2 respectively for the non-annealed and annealed sample. Moreover, no Schottky-like anomaly is observed for

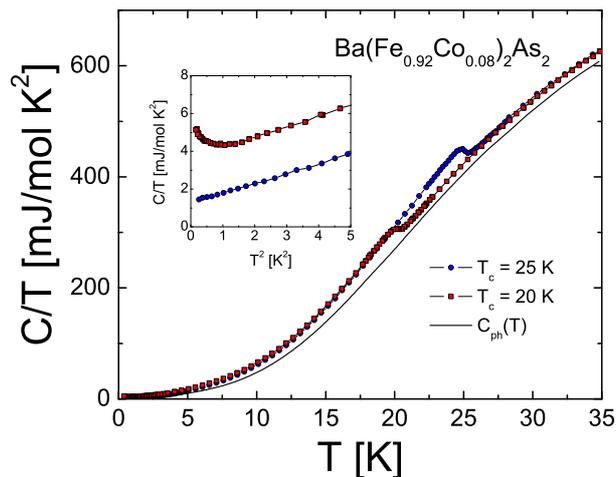


Figure 1. (Color online) The temperature dependence of the heat capacity of $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$ samples. Circles: annealed sample with $T_c = 25$ K. Squares: non-annealed sample with $T_c = 20$ K. The solid line describes the normal state specific heat (see text). Inset: low-temperature specific heat of these two materials.

the annealed sample. The considerably increase of T_c , decrease of γ_0 and lack of Schottky-type contribution at low temperature indicate significant improvement of the quality of the single crystals after the heat treatment.

In order to obtain the electronic part of the specific heat, we have used the same approach used previously for the optimal and doped $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ samples (see Ref.[5, 6]). We have assumed that the phonon contribution of the specific heat is independent of doping and we use the lattice specific heat obtained from the parent compound. We separate the lattice contribution to the specific heat of the pure Ba122 compound as $C_{ph} = C^{\text{BaFe}_2\text{As}_2} - \gamma_{el}^{\text{BaFe}_2\text{As}_2}T$ where $\gamma_{el}^{\text{BaFe}_2\text{As}_2}$ is the $T \rightarrow 0$ intercept of C/T of BaFe_2As_2 as shown by a solid line in Fig.1. So, the electronic specific heat is simply determined by $C_{el}(T)^{\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2} = C_p(T)^{\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2} - C(T)_{ph}$. The obtained normal state $\gamma(T)$ from above T_c provide perfect entropy balance for the electronic specific heat in the superconducting state below T_c for both, non-annealed[5] and annealed samples.

Fig.2 shows the electronic part of the specific heat of $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ samples. For the non-annealed sample a small Schottky contribution below 1 K has also been subtracted. For both samples pronounced peaks are observed at the transition temperature. For the annealed sample the specific heat exhibits a jump $\Delta C/T_c = 33.6 \text{ mJ/mol K}^2$ at T_c . Taking $\gamma_n = 22 \text{ mJ/mol K}^2$ the ratio $\Delta C/T_c\gamma = 1.53$ is slightly larger than the weak-coupling BCS value 1.43. It is also larger than $\Delta C/T_c\gamma = 1.34$ obtained for the non-annealed sample[5].

Below T_c the C_{el}/T data in Fig.2 were analyzed by the BCS α -model:

$$C_{BCS} = t \frac{d}{dt} \int_0^\infty dy \left(-\frac{6\gamma\Delta_0}{k_B\pi} \right) [f \ln f + (1-f) \ln(1-f)] \quad (1)$$

where $t = \frac{T}{T_c}$, f is the Fermi function $f = \frac{1}{e^{\frac{E}{k_B T}} + 1}$, $E = \sqrt{\epsilon^2 + \Delta^2}$ and $y = \frac{\epsilon}{\Delta}$ (see Ref.[13]) plus residual normal state component.

As has been shown before a single s -wave gap scenario cannot describe the specific heat data

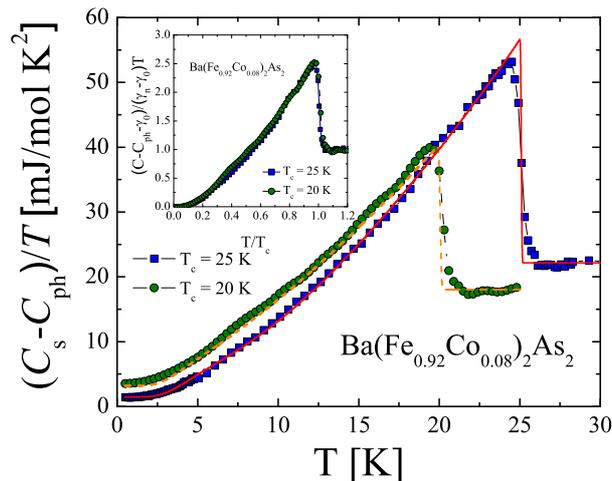


Figure 2. (Color online) The temperature dependence of the non-lattice part of the specific heat of $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$ samples. Solid and dashed lines are fits of the BCS α -model (see text). Inset: normalized temperature dependence of the superconducting part of the specific heat.

in Co-doped Ba122 material[5, 7, 6, 8]. It clearly indicates the presence of an anisotropic gap structure in this material. Moreover, the specific heat data of optimally doped Ba122 cannot be accounted by using a clean d-wave gap approach either[5, 7, 8]. In order to sufficiently describe the specific heat data of annealed $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$ two separate *s*-wave gaps (solid line) have been used as shown in Fig.2. This parametrization is not unique but provides a reasonable estimate of the dominant energy scales in the gap structure. It gives parameters: $\Delta_1 = 1.83$ meV, $\Delta_2 = 4.76$ meV and $A = 0.72$. The values of the gap are larger than the ones observed in non-annealed materials[5, 7] $\Delta_1 = 1.65$ meV, $\Delta_2 = 3.75$ meV and $A = 0.62$ (see dashed line in Fig.2). It is consistent with the lower transition temperature observed in the non-annealed materials. Inset of Fig.2 presents the electronic part of the specific heat of the superconducting portion of the $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$ samples. It has been obtained by subtracting the residual linear term γ_0 , together with a small Schottky contribution below 1 K for the non-annealed sample, and normalized by $(\gamma_n - \gamma_0)$. Interestingly, these two curves match, indicating no significant change of the gap structure in these two samples.

4. Summary and conclusions

In summary, using the low-temperature specific heat we explore details of the superconducting state of $\text{Ba}(\text{Fe}_{0.92}\text{Co}_{0.08})_2\text{As}_2$ with $T_c = 25$ and 20 K. By subtracting the phonon specific heat the temperature dependence of the electronic specific heat has been studied. The temperature variation of C_{el} as well as its field dependence (not shown) cannot be described by a single isotropic *s*-wave gap, indicating the presence of an anisotropic gap structure in the system. The temperature variation of the electronic specific heat below T_c may be well described by the presence of two superconducting gaps, pointing to a complex gap structure in the system. It has been shown recently that for optimally Co-doped BaFe_2As_2 samples a minimum of two superconducting gaps are necessary to describe the temperature dependence of the electronic specific heat[5, 7, 6, 8]. Moreover, for these two optimally doped samples with different quality the details of the superconducting state do not change significantly. It is in agreement with the lack of doping dependence in $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ [6], indicating that the gap structure does not change significantly as a function of doping[6]. This does not address the possibility that accidental nodes may or may not be present and could be sample, doping, and/or material dependent.

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